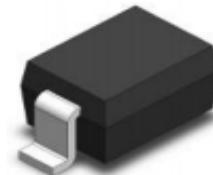


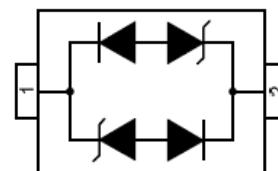
1-Line, Bi-directional, Transient Voltage Suppressors

Descriptions

The ESD24A003TA is a bi-directional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components that may be subjected to ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. It is particularly well-suited for cellular phones, portable device, digital cameras, power supplies and many other portable applications because of its small package and low weight.

The ESD24A003TA may be used to provide ESD protection up to $\pm 25\text{kV}$ air discharge $\pm 20\text{kV}$ contact discharge according to IEC61000 - 4 - 2, and withstand peak pulse current up to 6.0 A (8/20 μs) according to IEC61000-4-5.

**SOD-323**

**Circuit diagram**

Features

- Stand-off voltage: $\pm 24\text{ VMax}$
- Transient protection for each line according to
 - IEC61000-4-2 (ESD): $\pm 25\text{kV}$ air discharge $\pm 30\text{kV}$ contact discharge
 - IEC61000-4-5 (surge): 6.0A (8/20 μs)
- Solid-state silicon technology

Order information**Applications**

- Cell phone handsets and accessories
- Personal Digital Assistants (PDAs)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Digital Cameras
- MID/CAR DVD/MP3/MP4/PMP Players

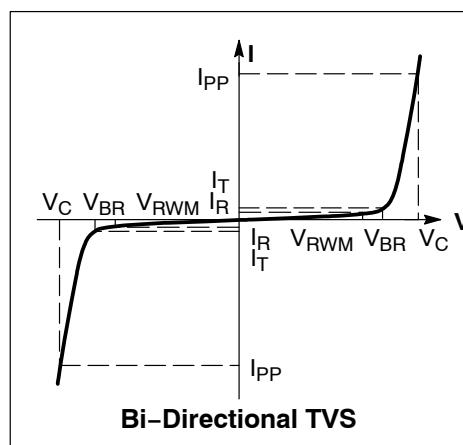
Device	Marking	Package	Shipping
ESD24A003TA	HC	SOD-323	3000/Tape&Reel

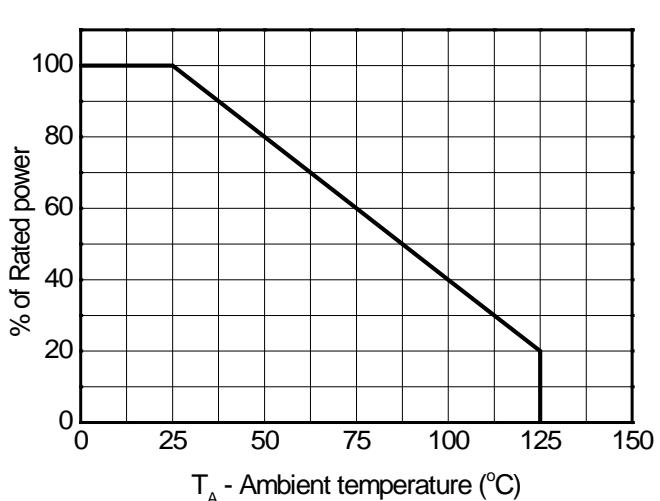
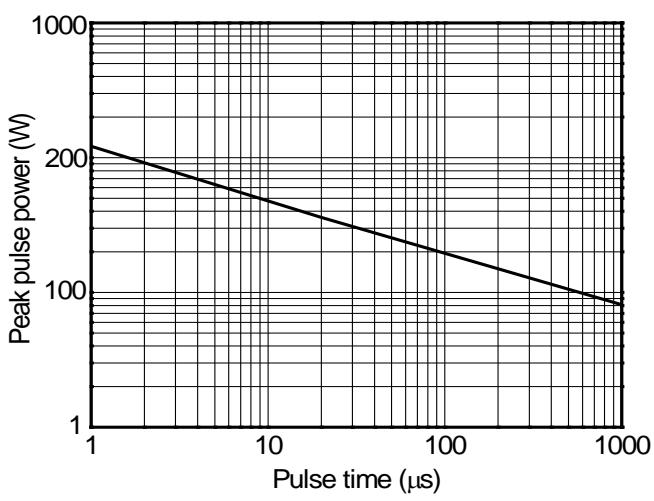
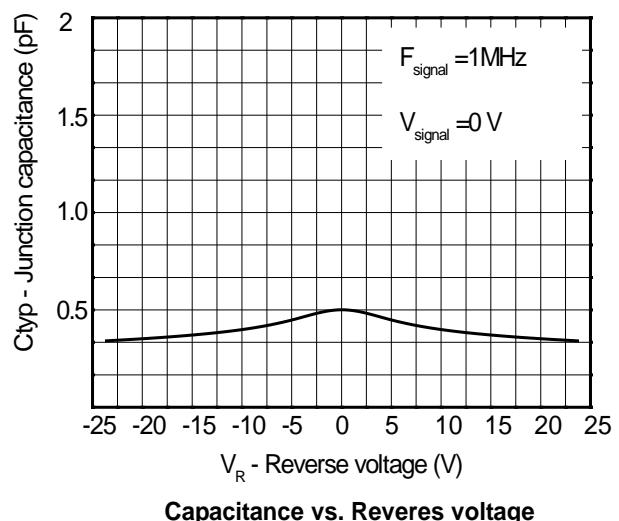
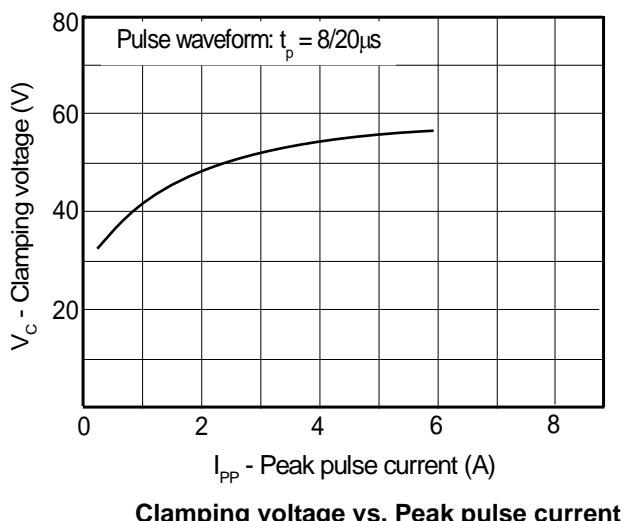
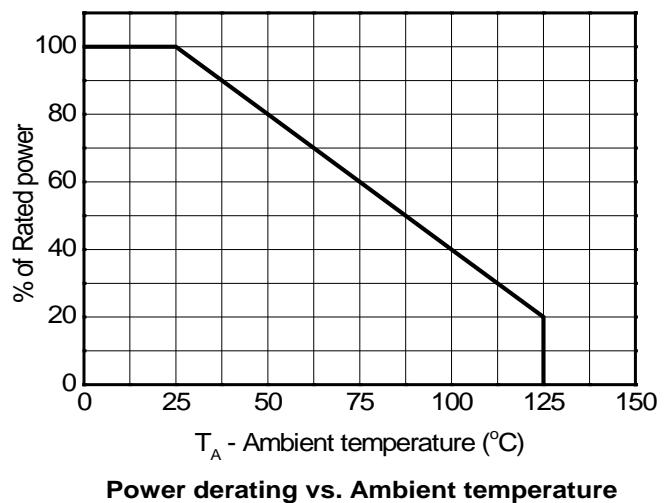
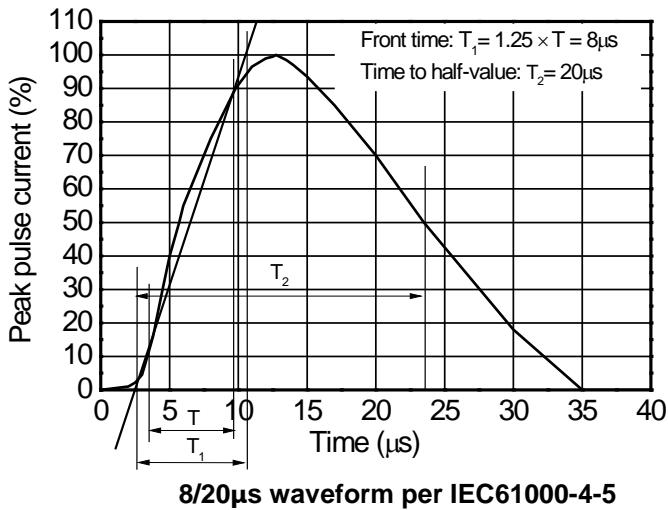
Absolute maximum ratings

Parameter	Symbol	Rating	Unit
Peak pulse current ($t_p = 8/20\mu s$)	I_{PP}	6.0	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	
Operation junction temperature	T_J	-55~150	°C
Lead temperature	T_L	260	°C
Storage temperature	T_{STG}	-55~150	°C

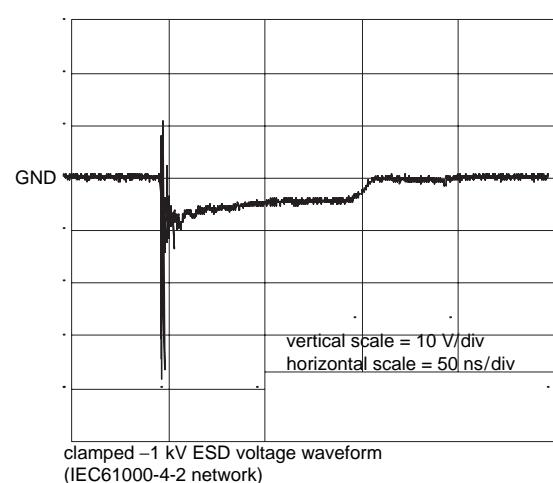
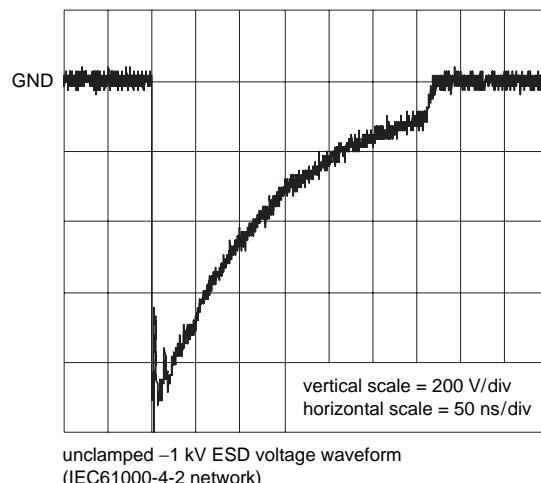
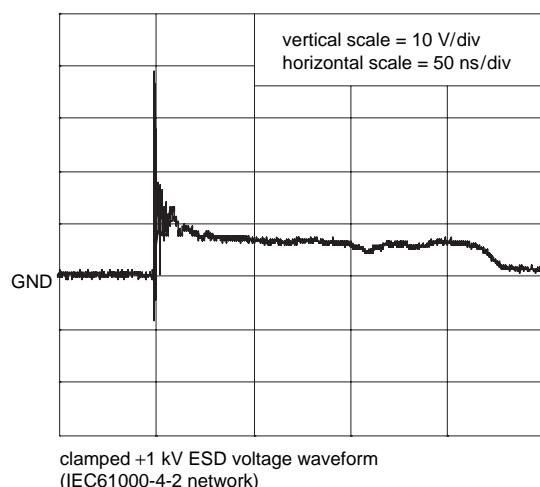
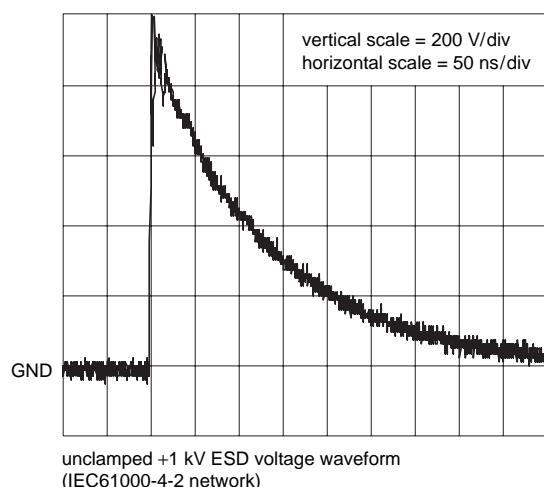
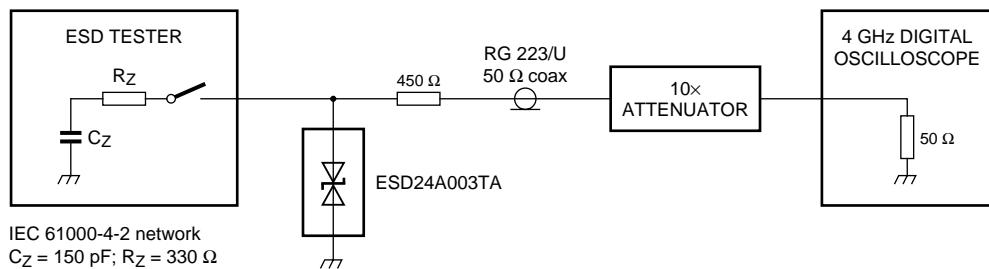
Electrical characteristics (TA=25 °C ,unless otherwise noted)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				± 24.0	V
Reverse leakage current	I_R	$V_{RWM} = 24$ V			1.0	μA
Reveres breakdown voltage	V_{BR}	$I_T=1mA$	25.0	26.0		V
Clamping voltage	V_C	$I_{PP}=1A$ tp=8/20us		36.0	38.0	V
		$I_{PP}=6A$ tp=8/20us		52.0	54.0	V
Junction capacitance	C_J	$V_R = 0V, f = 1MHz$		0.5	0.9	pF

Electrical performance curve V_C : Maximum clamping voltage V_{BR} : Reverse breakdown voltage V_{RWM} : Working voltage I_{PP} : Maximum peak current

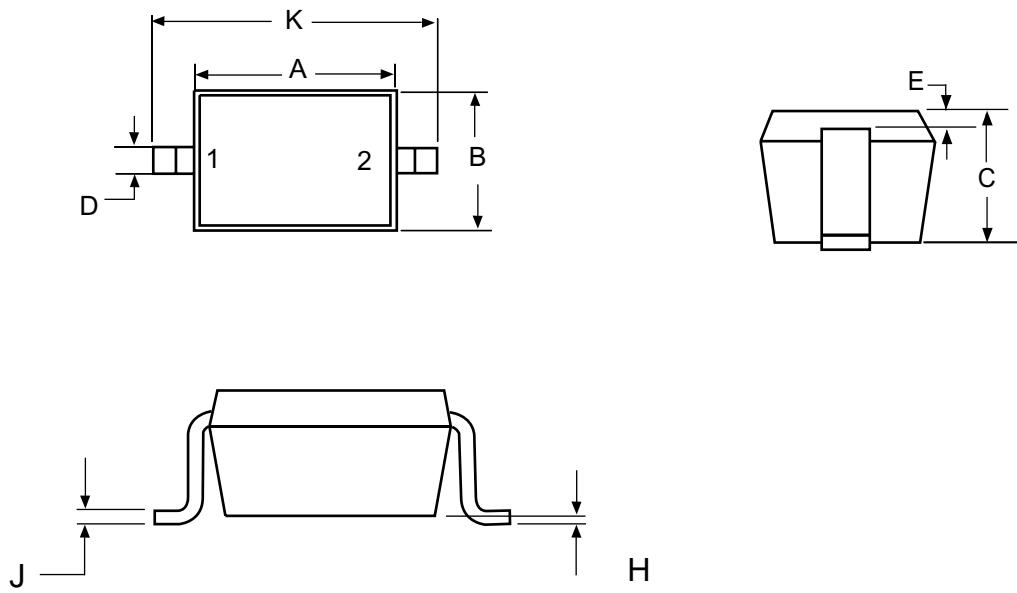


ESD clamping test setup and waveforms



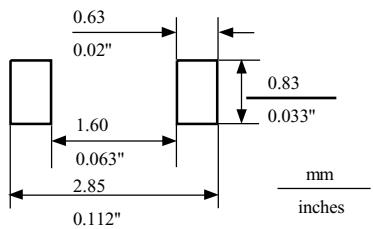
Package outline dimensions

SOD-323



Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	1.60	1.80	0.063	0.071
B	1.15	1.35	0.045	0.053
C	0.80	1.00	0.031	0.039
D	0.25	0.40	0.010	0.016
E	0.15 REF		0.006 REF	
H	0.00	0.10	0.000	0.004
J	0.089	0.177	0.0035	0.0070
K	2.30	2.70	0.091	0.106

Recommend land pattern (Unit: mm)



Note: This land pattern is for your reference only. Actual pad layouts may vary depending on application.